

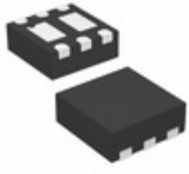

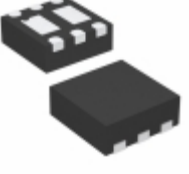
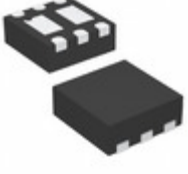
	<h2>SIA906EDJ-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SIA906EDJ-T1-GE3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET 2N-CH 20V 4.5A SC70-6</p> <p>Datenblätter:  SIA906EDJ-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 25124 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIA906EDJ-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET 2N-CH 20V 4.5A SC70-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	25124 pcs Stock
detaillierte Beschreibung	Mosfet Array 2 N-Channel (Dual) 20V 4.5A 7.8W
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	7.8W
Verpackung / Gehäuse	PowerPAK® SC-70-6 Dual
Supplier Device-Gehäuse	PowerPAK® SC-70-6 Dual
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4.5A
Rds On (Max) @ Id, Vgs	46 mOhm @ 3.9A, 4.5V
VGS (th) (Max) @ Id	1.4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	12nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	350pF @ 10V
Verpackung	Original-Reel®
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SIA906EDJ-T1-GE3DKR

SIA906EDJ-T1-GE3 ist neu im Original, Suche SIA906EDJ-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIA906EDJ-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SIA906EDJ-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SIA906EDJ-T1-E3 VISHAY VISHAY QFN-6</p>	 <p>SIA907EDJT VISHAY SIA907EDJT VISHAY</p>	 <p>SIA817EDJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 30V 4.5A SC-70-6</p>	 <p>SIA906EDJ-T4-GE3 VISHAY SIA906EDJ-T4-GE3 VISHAY</p>
 <p>SIA907EDJT-T4-GE3 VISHAY SIA907EDJT-T4-GE3 VISHAY</p>	 <p>SIA906EDJ-T1-GE3 Vishay / Siliconix MOSFET 2N-CH 20V 4.5A SC70-6</p>	 <p>SIA850DJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 190V 0.95A SC70-6</p>	 <p>SIA907EDJT-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V 4.5A SC-70-6L</p>

heiße Teile

Mehr

⊛ SIA456DJ-T1-GE3	↔ SIA456DJ-T1-GE3	⇒ SIA483DJ-T1-GE3	D SIA483DJ-T1-GE3	⇒ SIA513DJ-T1-E3
⊣ SIA517DJ-T1-GE3	⊛ SIA517DJ-T1-GE3	D SIA517DJ-T4-GE3	⇒ SIA519EDJ-T1-GE3	⇒ SIA519EDJ-T1-GE3
⊛ SIA533EDJ-T1-GE3	⊣ SIA533EDJ-T1-GE3	⊛ SIA778DJ-T1-GE3	↔ SIA778DJ-T1-GE3	⇒ SIA811ADJ-T1-GE3
D SIA811ADJ-T1-GE3	⊛ SIA811DJ-T1	⊣ SIA811DJ-T1-E3	⊛ SIA811DJ-T1-E3	⇒ SIA811DJ-T1-GE3
⇒ SIA811DJ-T1-GE3	↔ SIA813DJ-T1-GE3	⊛ SIA813DJ-T1-GE3	⊣ SIA814DJ-T1-GE3	⇒ SIA814DJ-T1-GE3
↔ SIA906EDJ-T1-GE3	⇒ SIA906EDJ-T4-GE3	D SIA907EDJT	⊛ SIA907EDJT-T1-GE3	⊣ SIA907EDJT-T1-GE3
⊛ SIA907EDJT-T4-GE3	D SIA910EDJ-T1-GE3	⇒ SIA910EDJ-T1-GE3	↔ SIA911ADJ-T1-GE3	⇒ SIA911ADJ-T1-GE3
⊣ SIA911ADJ-T5-GE3	⊛ SIA911DJ-T1-E3	↔ SIA911DJ-T1-E3	⇒ SIA911DJ-T1-GE3	⇒ SIA911DJ-T1-GE3
⊛ SIA911DJ-T5-GE3	⊣ SIA911EDJ-T1-GE3	⊛ SIA911EDJ-T1-GE3	D SIA912DJ	⇒ SIA912DJ-T1-GE3
↔ SIA912DJ-T1-GE3	⊛ SIA913ADJ-T1-GE3	⊣ SIA913ADJ-T1-GE3	⊛ SIA913DJ-T1-GE3	⇒ SIA913DJ-T1-GE3

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